

Bipolar Transistor

(-)15 V, (-)0.7 A, Low V_{CE}(sat), (PNP)NPN Single CP

2SB815, 2SD1048

Features

- Ultrasmall Package Allows Miniaturization in End Products
- Large Current Capacity (I_C=0.7 A) and Low-Saturation Voltage
- These are Pb-Free Devices

Specifications

(): 2SB815

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to Base Voltage	V _{CBO}		(-)20	V
Collector to Emitter Voltage	V _{CEO}		(–)15	V
Emitter to Base Voltage	V _{EBO}		(–)5	V
Collector Current	Ic		(-)0.7	Α
Collector Current (Pulse)	I _{CP}		(-)1.5	Α
Collector Dissipation	P _C		200	mW
Junction Temperature	Tj		125	°C
Storage Temperature	Tstg		-55 to +125	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

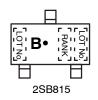
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- 1: Source
- 2: Drain
- 3: Gate

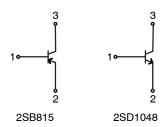
SC-59 / CP3 CASE 318BJ

MARKING DIAGRAMS





ELECTRICAL CONNECTION



ORDERING INFORMATION

Device	Package	Shipping [†]
2SB815-6-TB-E	SC-59 / CP3 (Pb-Free)	3000 / Tape & Reel
2SB815-7-TB-E	SC-59 / CP3 (Pb-Free)	3000 / Tape & Reel
2SD1048-6-TB-E	SC-59 / CP3 (Pb-Free)	3000 / Tape & Reel
2SD1048-7-TB-E	SC-59 / CP3 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

2SB815, 2SD1048

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$)

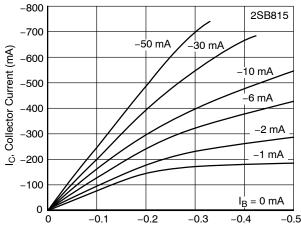
			Ratings			
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} = (-)15 V, I _E = 0 A	-	-	(-)0.1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} = (-)4 V, I _C = 0 A	-	-	(-)0.1	μΑ
DC Current Gain	h _{FE} 1	V _{CE} = (-)2 V, I _C = (-)50 mA	200*	-	600*	
	h _{FE} 2	V _{CE} = (-)2 V, I _C = (-)500 mA	80	-	-	
Gain-Bandwidth Product	f _T	V _{CE} = (-)10 V, I _C = (-)50 mA	_	250	-	MHz
Output Capacitance	Cob	V _{CB} = (-)10 V, f = 1 MHz	-	(13)8	-	pF
Collector to Emitter Saturation Voltage	V _{CE} (sat)1	$I_C = (-)5 \text{ mA}, I_B = (-)0.5 \text{ mA}$	-	(-15)10	(-35)25	mV
	V _{CE} (sat)2	I _C = (-)100 mA, I _B = (-)10 mA	-	(-60)30	(-120)80	mV

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

*The 2SB815/2SD1048 are classified by 50 mA h_{FE} as follows:

Rank	6	7	
h _{FE}	200 to 400	300 to 600	

2SB815, 2SD1048



 V_{CE} , Collector to Emitter Voltage (V)

Figure 1. I_C - V_{CE}

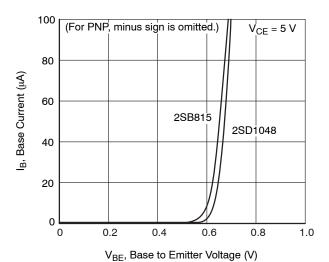


Figure 3. $I_B - V_{BE}$

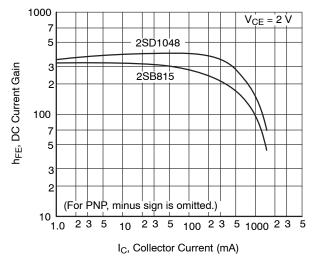
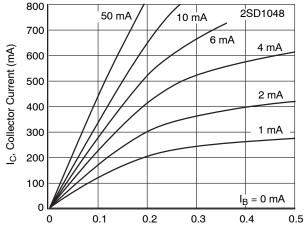


Figure 5. h_{FE} - I_C



V_{CE}, Collector to Emitter Voltage (V)

Figure 2. I_C - V_{CE}

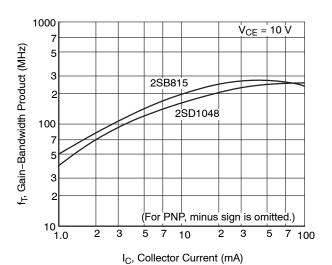


Figure 4. f_T - I_C

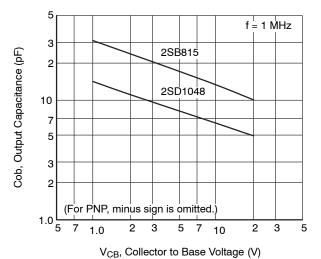


Figure 6. Cob – V_{CB}

2SB815, 2SD1048

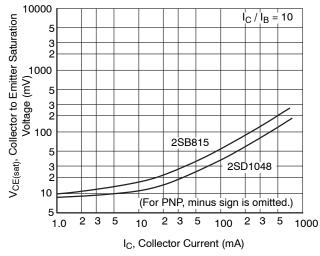


Figure 7. V_{CE(sat)} – I_C

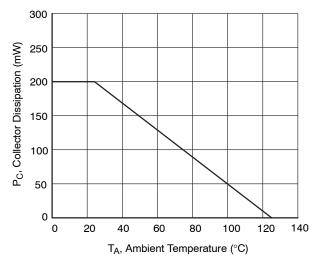


Figure 8. P_C – T_A

MECHANICAL CASE OUTLINE

3X L

зх b

⊕ 0.10 M C A

C SEATING PLANE

Α

E1

е





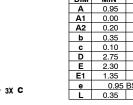
SC-59 / CP3 CASE 318BJ **ISSUE O**

DATE 09 JAN 2015

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER SIDE.
 4. DIMENSIONS D AND E1 ARE MEASURED AT THE OUTERMOST
- EXTREME OF THE PLASTIC BODY.
 DIMENSIONS 6 AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10 AND 0.20 FROM THE TIP.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.95	1.35	
A1	0.00	0.10	
A2	0.20	0.40	
b	0.35	0.50	
С	0.10	0.20	
D	2.75	3.05	
E	2.30	2.70	
E1	1.35	1.65	
е	0.95 BSC		
_	0.35	0.75	



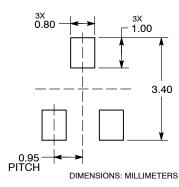
END VIEW

RECOMMENDED **SOLDERING FOOTPRINT***

SIDE VIEW

Δ1

TOP VIEW



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM



XXX = Specific Device Code

Μ = Date Code

= Pb-Free Package

(Note: Microdot may be in either location) *This information is generic. Please refer to

device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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